

# Adjustable Over-Voltage Protection Switch

#### **Features**

- Wide Input voltage range: 2.7V to 30V
- Up to 3.0A current capability
- Integrated 60mΩ (typ) N-Channel MOSFET
- Fast OVP turn-off response time: 100ns
- Flexible trip-point options
  - ▶ Default Fixed 6.05
  - ▶ Adj. 4V to 22V
- Auto-enabled switch with 18ms debounce time
- Under voltage (UVLO), Short-circuit and thermal shutdown protection
- Compliance to IEC61000-4-2 (level 4)
- ► Contact: ±8kV
- ► Air Gap: ±15kV
- ESD Protection
  - ► Human Body Model: ±2.5kV
- Pb-free UDFN-8 package and WLCSP-6 packages
- -40°C to +85°C Temperature Range

### **Brief Description**

The KTS1670 over-voltage protection device features an ultra-low  $60m\Omega$  (typical) on-resistance high current integrated MOSFET which actively protects low-voltage systems from voltage supply faults up to +30V.

An input voltage exceeding the over-voltage threshold will cause the internal MOSFET to turn off, preventing excessive voltage from damaging downstream devices.

When the OVLO input is connected to GND, the KTS1670 automatically chooses the internal fixed OVLO threshold, preset to 6.05V (typical). The over-voltage protection threshold can be adjusted with an optional external resistor divider to a voltage between 4V and 22V.

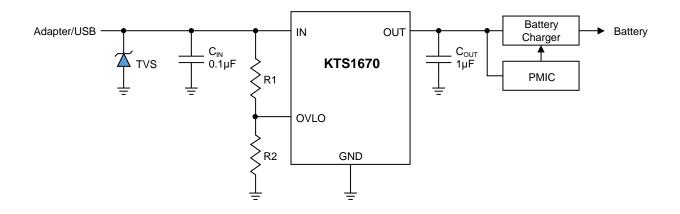
In case the device temperature exceeds the maximum junction temperature, the device switches off.

The KTS1670 is available in a RoHS and Green compliant 8-lead 2.0 x 2.0 x 0.5mm UDFN and 6-Bump 1.20 x 1.00mm WLCSP packages.

## **Applications**

- Smartphones
- Mobile Internet Devices
- Tablet Computers
- Peripherals
- STB

## **Typical Application**

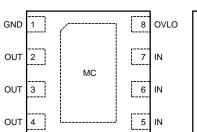




### **Pin Descriptions**

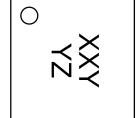
UDFN	WLCSP	Name	Function
5, 6, 7	A2, B2	IN	Voltage Input. Bypass IN with 0.1µF capacitor as close as possible to the device.
8	C2	OVLO	External OVLO adjustment. Connect OVLO to GND when using the internal threshold. Connect a resistor-divider to OVLO to set a different OVLO threshold.
1	C1	GND	Ground.
2, 3, 4	A1, B1	OUT	Output Voltage
MC	_	MC	Metal chassis. Connect to ground for electrical and thermal usage. MC is internally connected to Analog Ground pin.

### **UDFN22-8**



TOP VIEW

TOP VIEW

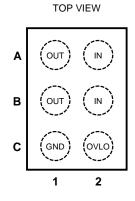


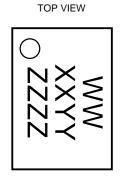
8-Lead 2.00mm x 2.00mm x 0.5mm UDFN Package

#### **Top Mark**

XX = Device Code YY = Date Code, Z = Assembly Code

#### **WLCSP-6**





6-Bump 1.20mm x 1.00mm x 0.6mm WLCSP Package

#### Top Mark

WW = Device ID Code, XX = Date Code, YY = Assembly Code, ZZZZ = Serial Number



## Absolute Maximum Ratings<sup>1</sup>

#### $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Description	Value	Units
IN	Input voltage	-0.3 to 30	V
OUT	Output voltage	-0.3 to VIN+0.3	V
OVLO	OVLO Pin	-0.3 to 7	V
IN, OUT Current	Continuous Current	3.0	Α
TJ	Operating Temperature Range	-40 to 150	°C
Ts	Storage Temperature Range	-65 to 150	°C
T <sub>LEAD</sub>	Maximum Soldering Temperature (at leads, 10 sec)	260	°C

## **Thermal Capabilities**

Symbol	Description	Value	Units	
WLCSP-6				
θја	Thermal Resistance – Junction to Ambient <sup>2</sup>	107	°C/W	
P <sub>D</sub>	Maximum Power Dissipation at T <sub>A</sub> ≤ 25°C	1170	mW	
ΔΡ <sub>D</sub> /ΔΤ	Derating Factor Above T <sub>A</sub> = 25°C	-9.4	mW/°C	
UDFN22-8				
θЈА	Thermal Resistance – Junction to Ambient <sup>2</sup>	90	°C/W	
PD	Maximum Power Dissipation at T <sub>A</sub> ≤ 25°C	1380	mW	
ΔΡ <sub>D</sub> /ΔΤ	Derating Factor Above T <sub>A</sub> = 25°C	-6.5	mW/°C	

## **Ordering Information**

Part Number	Marking	Operating Temperature	Package
KTS1670EUN-TR	KEXXYYZZZZ <sup>3</sup>	-40°C to +85°C	WLCSP-6
KTS1670EDA-TR	KEYYZ <sup>4</sup>	-40°C to +85°C	UDFN22-8

### Recommended Operating Range<sup>5</sup>

Description	Value
Input voltage range	2.7V to 22V
Input to output continuous current	2A
Output capacitance range	Up to 100µF

<sup>1.</sup> Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

<sup>2.</sup> Junction to Ambient thermal resistance is highly dependent on PCB layout. Values are based on thermal properties of the device when soldered to an EV board.

<sup>3.</sup> XX = Date Code, YY = Assembly Code, ZZZZ = Serial Number.

<sup>4.</sup> YYZ = Date Code and Assembly Code.

<sup>5.</sup> The device is not guaranteed to function outside of recommended operating condition.



### Electrical Characteristics<sup>6</sup>

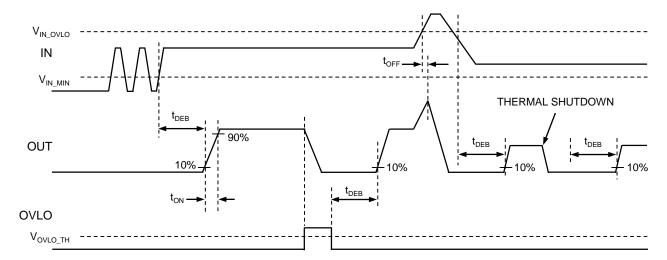
Unless otherwise noted, the *Min* and *Max* specs are applied over the full operation temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C, while *Typ* values are specified at room temperature (25°C).  $V_{IN} = 5.0V$ ,  $I_{IN} \le 3A$ 

Symbol	Description	Conditions	Min	Тур	Max	Units
INPUT Oper	ation		•		•	
I <sub>IN</sub>	Input supply current	VIN = 5V, VIN < VIN_OVLO			120	μА
V <sub>IN_UVLO</sub>	Under voltage lockout threshold	V <sub>IN</sub> rising		2.3		V
V <sub>UVLO_HYST</sub>	Under voltage lockout hysteresis			0.1		V
OVP						
V <sub>IN_OVLO</sub>	Internal over voltage trip level	V <sub>IN</sub> rising		6.05		V
VIN_OVLO_HYS	OVLO Hysteresis	V <sub>IN</sub> falling		0.10		V
V	OVLO preset threshold range		1.185	1.215	1.245	V
$V_{OVLO\_TH}$	Adjustable OVLO threshold range		4		22	V
Vovlo_sel	External OVLO select threshold		0.2		0.3	V
R <sub>DS(ON)</sub>	Switch On-Resistance	V <sub>IN</sub> = 5V, I <sub>IN</sub> = 1.0A, T <sub>A</sub> = +25°C		60		mΩ
lovlo	OVLO input leakage current	Vovlo = Vovlo_th	-120		120	nA
TIMING – Fi	gure 1		•	I.		
t <sub>DEB</sub>	Debounce time	Time from 2.5V $<$ V <sub>IN</sub> $<$ V <sub>IN_OVLO</sub> to V <sub>OUT</sub> = 10% of V <sub>IN</sub>		18		ms
ton	Switch turn-on time	$V_{\text{IN}} = 5V, \ R_{\text{L}} = 100\Omega, \ C_{\text{LOAD}} = 100 \mu F$ $V_{\text{OUT}} \ from \ 10\%, \ V_{\text{IN}} \ to \ 90\% \ V_{\text{IN}}$		2		ms
toff	Switch turn-off time	VIN > VIN_OVLO to VOUT stop rising		100		ns
ESD PROTE	CTION					
V	IEC61000-4-2 Contact discharge	IN and OUT pins. C <sub>IN</sub> = C <sub>OUT</sub> = 1µF		±8		kV
$V_{ESD}$	IEC61000-4-2 Air gap discharge	IN and OUT pins. C <sub>IN</sub> = C <sub>OUT</sub> = 1µF		±15		kV
All pins	Human Body Model(HBM) Model = 2			±2.5		kV
THERMAL SH	HUTDOWN					
t <sub>Ј</sub> -тн	IC junction thermal shutdown threshold			145		°C
	IC junction thermal shutdown hysteresis			20		°C

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<sup>6.</sup> KTS1670 is guaranteed to meet performance specifications over the  $-40^{\circ}$ C to  $+85^{\circ}$ C operating temperature range by design, characterization and correlation with statistical process controls.





<sup>\*</sup> NOTE: WAVEFORMS ARE NOT TO SCALE

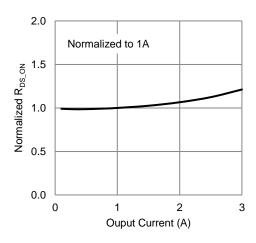
Figure 1. Timing Diagram



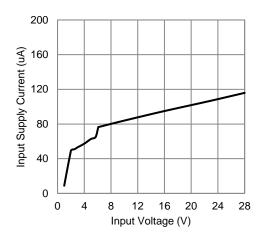
### **Typical Characteristics**

 $V_{IN} = 5V$ ,  $C_{IN} = 0.1 \mu F$ ,  $C_{OUT} = 1 \mu F$ , OVLO pin = GND,  $Temp = 25 ^{\circ}C$  unless otherwise specified.

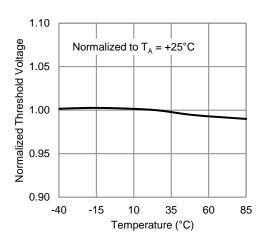
Normalized R<sub>DSON</sub> vs. Output Current



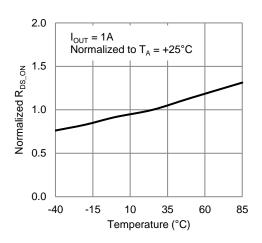
Input Supply Current vs. Input Voltage (no load)



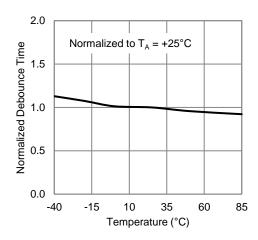
Normalized Fixed OVLO vs. Temperature (OVLO pin GND)



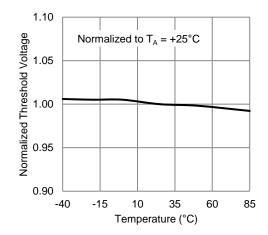
Normalized R<sub>DSON</sub> vs. Temperature



Normalized Debounce Time vs. Temperature



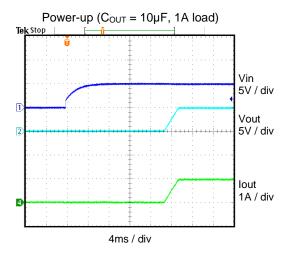
Normalized Adjustable OVLO Threshold vs. Temperature

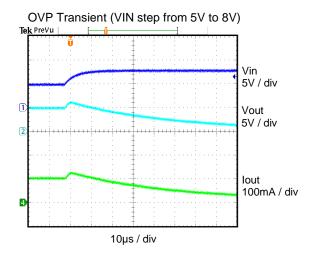




## **Typical Characteristics (continued)**

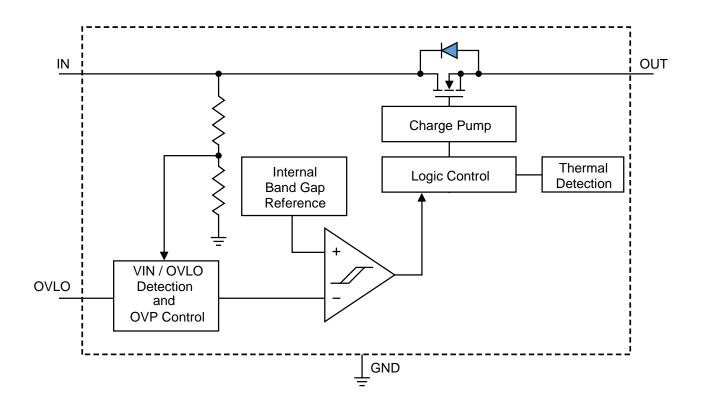
 $V_{IN} = 5V$ ,  $C_{IN} = 0.1 \mu F$ ,  $C_{OUT} = 1 \mu F$ , OVLO pin = GND, Temp = 25°C unless otherwise specified.







### **Functional Block Diagram**



### **Functional Description**

The KTS1670 is inserted between the power supply or charger source and the load to be protected. The KTS1670 consists of a slew-rate controlled, low resistance OVP switch, under-voltage lockout protection (UVLO), and over-voltage monitor and protection (OVLO).

The KTS1670 overvoltage protection device features a low on-resistance (R<sub>DSON</sub>) internal FET and protects low-voltage systems against voltage faults up to +30V. If the input voltage exceeds the overvoltage threshold, the internal FET is turned off to prevent damage to upstream components. The 18ms debounce time built into the device prevents false turn on of the internal FET during startup.

In normal operation the OVP switch acts as a slew-rate controlled load switch, connecting and disconnecting the power supply from IN to OUT. A low resistance N-Channel MOSFET is used to minimize the voltage drop between the voltage source and the load and to reduce power dissipation.

When the voltage at the input exceeds the programmed over-voltage trip point, the device immediately turns off the internal switch disconnecting the load from the abnormal voltage, preventing damage to downstream components.

In the event that the power dissipation causes the chip temperature to exceed its maximum temperature setting, the KTS1670 will switch off protecting the device. Once the chip temperature has cooled to below the hysteresis temperature, KTS1670 will re-initiate. Should the over-temperature condition persist, then KTS1670 will continue to thermally cycle on and off, until the input power is removed.

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#### **USB ON-The-Go (OTG) Operation**

When used in an OTG application the KTS1670 can provide power from OUT to IN. Initially, the OTG voltage applied at OUT will forward bias the power switch bulk diode and present a voltage drop of approximately 0.7V between OUT and IN. The maximum current in this mode is limited by the thermal performance of the device and at an ambient temperature of 25°C

$$IMAX = 1.17W/0.7V = 1.67A$$

This is purely a transitionary condition as once the voltage at IN exceeds the UVLO voltage of 2.3V and the debounce time of 18ms has elapsed, the main power switch will turn fully ON, significantly reducing the voltage drop from OUT to IN.

#### **UVLO (Under Voltage Lockout)**

The device has a built-in under voltage lock out (UVLO) circuit. When  $V_{IN}$  is rising, the output remains disconnected from the input until  $V_{IN}$  voltage is above 2.3V (nominal). This circuit has a 100mV hysteresis to provide noise immunity to transient conditions.

#### **OVLO (Over Voltage Lockout)**

The KTS1670 adjustable version has a 1.215V (typ) overvoltage trip threshold on the OVP pin. With a resistor divider on OVLO pin from IN to GND, the over-voltage protection point of IN can be adjusted between 4V and 22V. Fixed OVP products are available with an internal resistor divider providing 6.05V(typ), 9.98V (typ), or 13.5V (typ) OVLO threshold trip voltage. To activate the internal Fixed OVP, the OVLO pin should be connected to GND.

#### **Internal MOSFET Switch**

The KTS1670 incorporates an internal MOSFET with a  $60m\Omega$  (typ)  $R_{DS(ON)}$ . The MOSFET gate is driven by an integrated charge pump which generates the necessary voltage above IN.

#### **Thermal Protection**

The internal FET turns off when the junction temperature exceeds +145°C (typ). The device exits thermal shutdown after the junction temperature cools down by 20°C (typ).

### **Application Information**

#### **Input Capacitor**

A 0.1µF or larger capacitor is typically recommended for CIN. CIN should be located close to the device IN pin. Ceramic capacitors are recommended for CIN. Select capacitors with a voltage rating at least 5V higher than the maximum possible voltage during surge. 50V rated capacitors are ideal for most applications.

#### **Output Capacitor**

In order to ensure stability while the current limit is active, a small output capacitance of approximately 1µF is required at the output. The output capacitor has no specific capacitor ESR requirement. If desired, COUT may be increased to accommodate any load transient condition.

#### **External OVLO Adjustment**

If OVLO is connected to ground, the internal OVLO comparator uses the internally set OVLO value.

The adjustable threshold uses a 1.215V (typical) overvoltage trip threshold on the OVLO pin. With a resistor divider on the OVLO pin from IN to GND, the over-voltage protection point of IN can be adjusted between 4V and 22V. Once the OVLO pin voltage exceeds the OVLO select voltage, VovLo\_Select (0.25V typical), the comparator reads the OVLO pin voltage (a fraction of IN) set by the external resistor divider (R1, R2).

R1 =  $1M\Omega$  is a good starting value for minimum current consumption. Since  $V_{IN\_OVLO}$ ,  $V_{OVLO\_THRESH}$ , and R1 are known, R2 can be calculated from the following formula:

$$V_{IN_{O}VLO} = V_{OVLO_{TH}} \times (1+R1/R2) = 1.215V \times (1+R1/R2)$$

This external resistor-divider is completely independent from the internal resistor-divider.

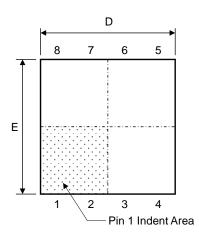
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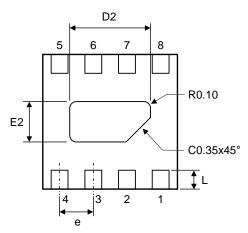
# **Packaging Information**

### UDFN22-8 (2.00mm x 2.00mm x 0.50mm)

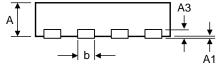
### **Top View**



#### **Bottom View**

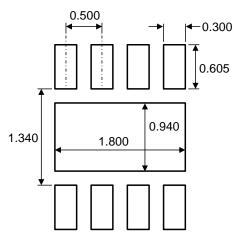


Dimension	mm			
Dimension	Min.	Тур.	Max.	
Α	0.45	0.50	0.55	
A1	0.00	0.02	0.05	
А3	0.130 REF.			
b	0.20	0.25	0.30	
D	1.90	2.00	2.10	
D2	1.15	1.20	1.25	
Е	1.90	2.00	2.10	
E2	0.55	0.60	0.65	
е	0.500 BSC			
L	0.23	0.28	0.33	



**Side View** 

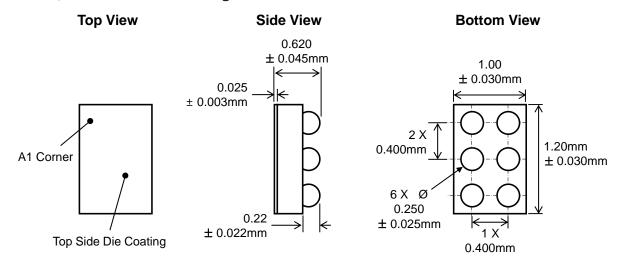
### **Recommended Footprint**



<sup>\*</sup> Dimensions are in millimeters.

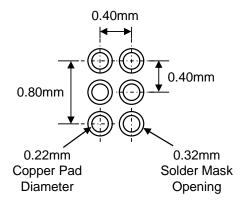


#### WLCSP-6, 1.2mm x 1.0mm Package



#### **Recommended Footprint**

#### (NSMD Pad Type)



<sup>\*</sup> Dimensions are in millimeters.

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